

Group theoretical analysis of double acceptors in a magnetic field: identification of the Si:B⁺ ground state

G. D. J. Smit,^{*} S. Rogge,[†] J. Caro, and T. M. Klapwijk

Department of NanoScience, Delft University of Technology, Lorentzweg 1, 2628 CJ Delft, The Netherlands

(Dated: February 2, 2008)

A boron impurity in silicon binding an extra hole is known to have only one bound state at an energy of just below 2 meV. The nature of the Si:B⁺ ground state is however not well established. We qualitatively analyze the behavior in a magnetic field of isolated acceptors in a tetrahedral lattice binding two holes using group theory. Applying these results, we analyze recent measurements and conclude that the ground state of B⁺ is most compatible with a non-degenerate Γ_1 state.

PACS numbers: 71.70.Ej, 03.65.Fd, 71.55.Cn, 71.70.Ch

INTRODUCTION

A neutral boron acceptor in silicon is able to weakly bind an extra hole, resulting in a positively charged ion (B⁺). This entity is an example of a positively charged acceptor, commonly denoted by A⁺, which is the counter part of the better known negatively charged donor D⁻. Both are related to their atomic-physics analogue, the negative hydrogen ion H⁻. The energy states associated with these ions are very shallow and spatially large. When their concentration is sufficiently high, their overlapping wave functions can form an upper Hubbard band [1] and they play an important role in electronic transport in semiconductors at low temperatures. Since a few years, electronic states of individual dopant atoms gained renewed interest due to their prospective application in Si-based solid state quantum computing [2].

Neither theoretically nor experimentally much work has been done on the B⁺-state. Optical spectroscopy is difficult due to the small ionization energy (less than 2 meV [3]). In particular, the nature of its ground state is not well-established and to our knowledge no results have been published on the magnetic field dependence of the energy levels.

The purpose of this paper is twofold. First, we present a general group-theoretical study of the magnetic field dependence of two-hole states in tetrahedral semiconductors. To our knowledge, such an analysis has not been published before. Second, because our analysis includes all possibilities for the B⁺ ground state, it enables us to compare our results with our recently published measurements of B⁺ in a magnetic field [4] and to draw conclusions about the nature of the B⁺ ground state.

BACKGROUND

The nature of the energy levels of a *neutral* boron acceptor (B⁰) in silicon is well-known [5] and the Zeeman effect in B⁰ has been studied in detail, both theoretically [6] and experimentally [7]. The B-impurity is located at substitutional sites of the tetrahedral silicon lattice. The

TABLE I: Character table for the double group $\bar{T}_d$.

	E	$\bar{E}$	$8C_3$	$8\bar{C}_3$	$3C_2$, $3\bar{C}_2$	$6S_4$	$6\bar{S}_4$	$6\sigma_d$, $6\bar{\sigma}_d$
Γ_1	1	1	1	1	1	1	1	1
Γ_2	1	1	1	1	1	-1	-1	-1
Γ_3	2	2	-1	-1	2	0	0	0
Γ_4	3	3	0	0	-1	1	1	-1
Γ_5	3	3	0	0	-1	-1	-1	1
Γ_6	2	-2	1	-1	0	$-\sqrt{2}$	$\sqrt{2}$	0
Γ_7	2	-2	1	-1	0	$\sqrt{2}$	$-\sqrt{2}$	0
Γ_8	4	-4	-1	1	0	0	0	0

(one-hole) ground-state is a 1s-like fourfold degenerate state that belongs to the Γ_8 representation of the tetrahedral double group $\bar{T}_d$ (for the nomenclature of representations used, see Table I). The bound hole has total angular momentum $j = \frac{3}{2}$. The single-hole wave function is the product of a 1s hydrogen-like envelope function and a band-like function. Due to spin-orbit interaction in silicon, the $j = \frac{1}{2}$ valence band is split off by ~ 43 meV [5] and does not need to be considered in first order. A magnetic field completely lifts the fourfold degeneracy and the lowest order Zeeman effect of the Γ_8 state is linear.

As far as symmetry is concerned, the B⁺-state is similar to neutral group-II acceptors in a tetrahedral lattice, which are well-studied (e.g. Ref. 8 and references therein). Coupling two $j = \frac{3}{2}$ (Γ_8) holes bound to a single nucleus gives rise to a six-fold degenerate state, because due to the Pauli-principle only the *anti*-symmetric part of $\Gamma_8 \times \Gamma_8$ must be taken into account. This can be reduced to its components as $\{\Gamma_8 \times \Gamma_8\} = \Gamma_1 + \Gamma_3 + \Gamma_5$. Interaction between the two holes can split the state into a non-degenerate Γ_1 state with total angular momentum $J = 0$ and a fivefold $\Gamma_3 + \Gamma_5$ state carrying $J = 2$.

Detailed quantitative calculations, which are necessary to establish the ordering and splitting of these levels, are very difficult to carry out, because of the many complicated physical effects that must be taken into account (valence band structure, crystal field, Jahn-Teller-effect,

etc.). Hund's rule, well-known from atomic physics, predicts that the more symmetric Γ_1 state has a higher energy than the $\Gamma_3 + \Gamma_5$ state, such that the latter is the ground state. The same conclusion was drawn from numerical calculations based on effective mass theory [9]. However, it has been shown that a dynamic Jahn-Teller effect can provide a mechanism to reverse the ordering of the levels [10, 11], leading to a Γ_1 ground state. This has in fact been observed in several neutral double acceptors.

Very little experimental work on B^+ has been done. The binding energy of the second hole in an isolated B^+ state has been measured in phonon-induced conductivity (PIC) measurements [3] and photoconductivity experiments [12]. It is slightly below 2 meV. Stress-dependence has been investigated with the same techniques [12, 13] and in one case the results were explained as evidence for a stress-induced ground state splitting [13]. However, interpretation of the conductivity data is non-trivial, because only levels which are very close to either the ground state of B^+ or the valence band edge can be observed with these techniques. Similar experiments in a magnetic field [14] showed a linear increase of the binding energy, which was ascribed to Landau level formation in the valence band. In these experiments, no additional shift or splitting was resolved.

Recent transport experiments in Si resonant tunneling devices provide a way to directly observe the magnetic field dependence of the B^+ state [4]. These experiments showed a super linear shift of the ground state towards the valence band (Fig. 2). Neither a ground state level-splitting nor bound excited states were observed.

DOUBLE ACCEPTORS IN A MAGNETIC FIELD

Here, we present a group theoretical study to qualitatively analyze the magnetic field behavior of isolated acceptors binding two holes in a tetrahedral semiconductor for various possible states. This analysis is not only applicable to neutral group-II acceptors (e.g. Zn in Ge), but also to group-III acceptors binding an extra hole and singly ionized group-I acceptors (e.g. Cu⁻ in Ge). After this general part, we return to the specific situation of B^+ .

We subsequently consider various possible two-hole levels and analyze their behavior in a magnetic field using perturbation theory. All such levels transform according to single-valued representations of T_d , as shown in the overview in Table II. We assume that the Coulomb force and spin-orbit interaction between the holes is sufficiently strong to split the levels into their irreducible components. Because of its possible importance for B^+ , we also consider the $\Gamma_3 + \Gamma_5$ level. In all cases it is assumed that the level under consideration is well separated from neighboring levels.

Furthermore, we briefly address the analogue of the

TABLE II: Overview of possible two-hole states arising from products of two single hole states and their reduction to irreducible representations of $\bar{T}_d$. For states originating from two *equivalent* single hole states (first two lines in the table), the Pauli principle allows only the antisymmetric part to be considered.

Combination	Two-hole states
$\{\Gamma_8 \times \Gamma_8\}$	$\Gamma_1 + \Gamma_3 + \Gamma_5$
$\{\Gamma_6 \times \Gamma_6\} = \{\Gamma_7 \times \Gamma_7\}$	Γ_1
$\Gamma_8 \times \Gamma'_8$	$\Gamma_1 + \Gamma_2 + \Gamma_3 + 2\Gamma_4 + 2\Gamma_5$
$\Gamma_6 \times \Gamma'_6 = \Gamma_7 \times \Gamma'_7$	$\Gamma_1 + \Gamma_4$
$\Gamma_8 \times \Gamma_7 = \Gamma_8 \times \Gamma_6$	$\Gamma_3 + \Gamma_4 + \Gamma_5$
$\Gamma_7 \times \Gamma_6$	$\Gamma_2 + \Gamma_5$

TABLE III: Character table for the double group $\bar{S}_4$ ($\omega = e^{i\pi/4}$).

	E	$\bar{E}$	C_2	$\bar{C}_2$	S_4	S_4^{-1}	$\bar{S}_4$	$\bar{S}_4^{-1}$
Γ_1	1	1	1	1	1	1	1	1
Γ_2	1	1	1	1	-1	-1	-1	-1
Γ_3	1	1	-1	-1	$-i$	i	$-i$	i
Γ_4	1	1	-1	-1	i	$-i$	i	$-i$
Γ_5	1	-1	$-i$	i	$-\omega$	ω^3	ω	$-\omega^3$
Γ_6	1	-1	i	$-i$	ω^3	$-\omega$	$-\omega^3$	ω
Γ_7	1	-1	$-i$	i	ω	$-\omega^3$	$-\omega$	ω^3
Γ_8	1	-1	i	$-i$	$-\omega^3$	ω	ω^3	$-\omega$

central field approximation in atomic physics, where it is assumed that each of the two holes moves in the field of the negative ionized acceptor core and the averaged effective potential due to the other hole. In this approximation, the symmetry of the field in which each hole moves is unaffected by the presence of the second hole. This method is known to give a good description for some group-II acceptors in Si and Ge [8].

When a magnetic field $\mathcal{B}$ is applied, new terms are introduced in the Hamiltonian of the holes, as given by

TABLE IV: Character table for the double groups $\bar{C}_3$ (left; $\omega = e^{i\pi/3}$) and $\bar{C}_{1h}$ (right).

	E	$\bar{E}$	C_3	C_3^{-1}	$\bar{C}_3$	$\bar{C}_3^{-1}$
Γ_1	1	1	1	1	1	1
Γ_2	1	1	$-\omega$	ω^2	$-\omega$	ω^2
Γ_3	1	1	ω^2	$-\omega$	ω^2	$-\omega$
Γ_4	1	-1	$-\omega^2$	ω	ω^2	$-\omega$
Γ_5	1	-1	ω	$-\omega^2$	$-\omega$	ω^2
Γ_6	1	-1	-1	-1	1	1

	E	$\bar{E}$	σ_h	$\bar{\sigma}_h$
Γ_1	1	1	1	1
Γ_2	1	1	-1	-1
Γ_3	1	-1	$-i$	i
Γ_4	1	-1	i	$-i$

TABLE V: Reduction of the representations of T_d when a magnetic field is applied along a $\langle 100 \rangle$, $\langle 111 \rangle$, or $\langle 110 \rangle$ direction of the tetrahedral lattice. From this table it can be deduced how the double acceptor levels split in a magnetic field.

Direction	$\langle 100 \rangle$	$\langle 111 \rangle$	$\langle 110 \rangle$
Group	S_4	C_3	C_{1h}
$\Gamma_1 (T_d)$	Γ_1	Γ_1	Γ_1
$\Gamma_2 (T_d)$	Γ_2	Γ_1	Γ_2
$\Gamma_3 (T_d)$	$\Gamma_1 + \Gamma_2$	$\Gamma_2 + \Gamma_3$	$\Gamma_1 + \Gamma_2$
$\Gamma_4 (T_d)$	$\Gamma_1 + \Gamma_3 + \Gamma_4$	$\Gamma_1 + \Gamma_2 + \Gamma_3$	$\Gamma_1 + 2\Gamma_2$
$\Gamma_5 (T_d)$	$\Gamma_2 + \Gamma_3 + \Gamma_4$	$\Gamma_1 + \Gamma_2 + \Gamma_3$	$2\Gamma_1 + \Gamma_2$

the Zeeman-Hamiltonian

$$\mathcal{H}_Z = -\mu_B(\mathbf{L} + 2\mathbf{S}) \cdot \mathbf{B} - \frac{1}{2}m^*\mu_B^2\{(\mathbf{r}_1^2 + \mathbf{r}_2^2)\mathcal{B}^2 - [(\mathbf{r}_1 + \mathbf{r}_2) \cdot \mathbf{B}]^2\},$$

where m^* is the hole effective mass and $\mathbf{L}$ and $\mathbf{S}$ are the total orbital and spin angular momenta in units of $\hbar$. The quantity $\mathbf{L} + 2\mathbf{S}$ is the total static magnetic moment of the system. Moreover, μ_B is the Bohr magneton and $\mathbf{r}_i$ is the position vector of the i -th hole.

The symmetry group of the Zeeman Hamiltonian $\mathcal{H}_Z$ is $\bar{C}_{\infty h}$. Unless $\mathbf{B}$ is directed along one of the main crystallographic axes, the symmetry group of the total Hamiltonian $\mathcal{H} = \mathcal{H}_0 + \mathcal{H}_Z$ reduces to the trivial group. When $\mathbf{B}$ is parallel to a $\langle 100 \rangle$, $\langle 111 \rangle$ or $\langle 110 \rangle$ direction in the crystal, the symmetry group of the total Hamiltonian reduces from $\bar{T}_d$ to $\bar{S}_4$, $\bar{C}_3$ or $\bar{C}_{1h}$, respectively. The relevant character tables are given in Table III and IV. Because all resulting groups are Abelian (commutative), it follows that the application of a magnetic field completely removes the degeneracy of all levels [19]. The way in which the Γ_i levels exactly split in a magnetic field is presented in Table V.

To deduce the magnetic field induced splitting of the levels, we employ first order degenerate perturbation theory. As mentioned before, it is assumed that the separation of the levels is large compared to the splitting caused by the field, so only the subspace of Hilbert space connected to the level under consideration needs to be taken into account. Given a set of basis functions $|i\rangle$ for a particular level, we find the corresponding sub-matrix $\langle i|\mathcal{H}_Z|j\rangle$ of $\mathcal{H}_Z$ and diagonalize it to obtain the splitting as a function of $\mathbf{B}$.

Instead of trying to calculate matrix elements from $\mathcal{H}_Z$ (after choosing a suitable set basis functions) it is much more convenient to use the well-established approach of constructing an *effective Zeeman Hamiltonian* [15]. This comprises the construction of a matrix of the required size, exploiting required symmetries to find vanishing elements and relations between elements. The result is a matrix that usually depends on a small number of un-

known phenomenological parameters, in terms of which the level splitting can be expressed. This approach is especially advantageous in the present situation, where both the values of the parameters occurring in $\mathcal{H}_Z$ and the unperturbed wave functions are not (exactly) known.

LINEAR ZEEMAN EFFECT

In this section, we will investigate the first order Zeeman effect of all the double acceptor levels mentioned before.

The Γ_i -levels

Because Γ_4 occurs in neither of the anti-symmetric direct products $\{\Gamma_i \times \Gamma_i\}$ ($i = 1 \dots 3$), the effective Hamiltonian matrix $\mathcal{H}_{\text{eff,lin}}$ vanishes identically for the three levels Γ_i . Hence, none of these levels experiences a linear Zeeman effect.

The linear part of the effective Zeeman Hamiltonian for a Γ_4 or Γ_5 level is given by [6, 16]

$$\mathcal{H}_{\text{eff,lin}} = \mu_B g(\mathcal{B}_x J_x + \mathcal{B}_y J_y + \mathcal{B}_z J_z).$$

Here, μ_B is the Bohr-magneton and J_x , J_y and J_z are matrix representations of the components of the angular momentum operator with respect to some convenient basis. The components J_α ($\alpha = x, y, z$) transform according to the Γ_4 representation of $\bar{T}_d$. Because $\{\Gamma_4 \times \Gamma_4\} = \{\Gamma_5 \times \Gamma_5\} = \Gamma_4$, the Γ_4 and Γ_5 level do have a linear Zeeman effect. Calculating the eigenvalues of the matrix $[\mathcal{H}_{\text{eff,lin}}]_i$ ($i = 4, 5$) yields

$$\Delta E = \begin{cases} +\mu_B g \mathcal{B} \\ 0 \\ -\mu_B g \mathcal{B} \end{cases}$$

The eigenvalues are independent of the direction of the magnetic field and hence give rise to an isotropic splitting.

The $\Gamma_3 + \Gamma_5$ level

The situation where the zero-field splitting of the $\Gamma_3 + \Gamma_5$ level is small compared to the Zeeman energy must be dealt with separately. Because $\Gamma_3 \times \Gamma_5 = \Gamma_4 + \Gamma_5$ contains Γ_4 , there are non vanishing cross-terms in the linear effective Zeeman Hamiltonian for a $\Gamma_3\Gamma_5$ -level. Therefore, such a level will have a linear Zeeman shift different from that of the individual Γ_3 and Γ_5 levels. The Hamiltonian sub-matrix for the $\Gamma_3 + \Gamma_5$ level is given by

[20]

$$\left(\begin{array}{c|ccc} \emptyset & -\frac{\sqrt{3}}{2}a_{35}\mathcal{B}_x & \frac{\sqrt{3}}{2}a_{35}\mathcal{B}_y & 0 \\ \hline -\frac{\sqrt{3}}{2}a_{35}\mathcal{B}_x & -\frac{1}{2}a_{35}\mathcal{B}_x & & \\ \frac{\sqrt{3}}{2}a_{35}\mathcal{B}_y & -\frac{1}{2}a_{35}\mathcal{B}_y & & \\ 0 & a_{35}\mathcal{B}_z & & \end{array} \right),$$

where a_{35} is assumed to be real. This 5×5 -matrix is given with respect to a basis with two Γ_3 wave functions and three Γ_5 -wave functions. Only the matrix-elements connecting Γ_3 functions to Γ_5 functions are shown explicitly. The upper left and bottom right parts are the matrices of the individual Γ_3 and Γ_5 level, respectively, as given in the previous subsection.

From this matrix, we determine the eigenvalues for $\mathcal{B}$ parallel to the main crystallographic directions. For $\mathcal{B} \parallel \langle 100 \rangle$, so $\mathcal{B}_x = \mathcal{B}$, $\mathcal{B}_y = \mathcal{B}_z = 0$, we find

$$\Delta E = \begin{cases} 0 \\ \pm \mu_B g \mathcal{B} \\ \pm a_{35} \mathcal{B}. \end{cases}$$

For $\mathcal{B} \parallel \langle 111 \rangle$, so $\mathcal{B}_x = \mathcal{B}_y = \mathcal{B}_z = \mathcal{B}/\sqrt{3}$, we have

$$\Delta E = \begin{cases} 0 \\ \pm \frac{1}{2} \mu_B g \mathcal{B} \pm \frac{1}{2} \mathcal{B} \sqrt{\mu_B^2 g^2 + 2a_{35}^2}. \end{cases}$$

Finally for $\mathcal{B} \parallel \langle 110 \rangle$, so $\mathcal{B}_x = \mathcal{B}_y = \mathcal{B}/\sqrt{2}$ and $\mathcal{B}_z = 0$, it is found that

$$\Delta E = \begin{cases} 0 \\ \pm \frac{1}{2} a_{35} \mathcal{B} \\ \pm \frac{1}{2} \mathcal{B} \sqrt{2\mu_B^2 g^2 + 3a_{35}^2}. \end{cases}$$

We conclude that there is indeed a linear Zeeman effect in the $\Gamma_3 + \Gamma_5$ level and the size of the effect is dependent of the direction of the field with respect to the crystal.

QUADRATIC ZEEMAN EFFECT

For some of the levels we will also give a second order approach, using the quadratic part of the effective Hamiltonian $\mathcal{H}_{\text{eff,quad}}$. Note that $\mathcal{H}_{\text{eff,quad}}$ contains both a second order approach to the linear part of the original $\mathcal{H}_Z$ and a first order approach to the quadratic part of the original $\mathcal{H}_Z$.

The Γ_1 and Γ_2 levels

For the Γ_1 level, the effective quadratic Zeeman Hamiltonian contains only one term and is straightforwardly given by

$$\mathcal{H}_{\text{eff,quad}} = a_1 \mathcal{B}^2,$$

where a_1 is a phenomenological parameter. The simple conclusion is that a Γ_1 level will experience a quadratic shift, independent of the direction of the magnetic field: $\Delta E = a_1 \mathcal{B}^2$. From this purely symmetry-based analysis, conclusions can be drawn neither about the magnitude of a_1 nor about its sign (that is, whether the state is diamagnetic or paramagnetic). Because $\Gamma_2 \times \Gamma_2 = \Gamma_1$, a similar expression holds for a Γ_2 level.

The Γ_3 level

For a Γ_3 level, the effective Hamiltonian contains two unknown parameters and is given by [8, 17]

$$\mathcal{H}_{\text{eff,quad}} = a_3 \mathcal{B}^2 + b_3 \left[-(2\mathcal{B}_z^2 - \mathcal{B}_x^2 - \mathcal{B}_y^2) \sigma_x + \sqrt{3}(\mathcal{B}_x^2 - \mathcal{B}_y^2) \sigma_y \right],$$

where σ_x and σ_y are Pauli spin matrices and a_3 and b_3 are phenomenological parameters. When $\mathcal{B} \parallel \langle 100 \rangle$ the eigenvalues are given by

$$\Delta E = (a_3 \pm 2b_3) \mathcal{B}^2.$$

This is a symmetric quadratic splitting superimposed on a quadratic shift. When $\mathcal{B} \parallel \langle 111 \rangle$, there is only one eigenvalue

$$\Delta E = a_3 \mathcal{B}^2,$$

meaning that there is no splitting in second order and the quadratic shift is the same as for $\mathcal{B} \parallel \langle 100 \rangle$. Finally, for $\mathcal{B} \parallel \langle 110 \rangle$, we find the eigenvalues

$$\Delta E = (a_3 \pm b_3) \mathcal{B}^2.$$

The Zeeman effect for this field direction is similar to $\mathcal{B} \parallel \langle 100 \rangle$, but the splitting is twice as small.

The Γ_4 and Γ_5 levels

Because the symmetrized squares of Γ_4 and Γ_5 satisfy $[\Gamma_4 \times \Gamma_4] = [\Gamma_5 \times \Gamma_5]$, the results for the Γ_4 and Γ_5 levels are similar. For these two levels, the quadratic part of the effective Zeeman Hamiltonian has three unknown parameters a_i , b_i and c_i ($i = 4, 5$) and is given by [6]

$$\begin{aligned} \mathcal{H}_{\text{eff,quad}} = & a_i \mathcal{B}^2 \\ & + b_i [3(\mathcal{B}_x^2 J_x^2 + \mathcal{B}_y^2 J_y^2 - \mathcal{B}_z^2 J_z^2) - 2\mathcal{B}^2] \\ & + c_i [\mathcal{B}_y \mathcal{B}_z \{J_y, J_z\} + \mathcal{B}_x \mathcal{B}_z \{J_x, J_z\} \\ & + \mathcal{B}_x \mathcal{B}_y \{J_x, J_y\}], \end{aligned}$$

where $\{A, B\} = \frac{1}{2}(AB + BA)$ denotes the anti-commutator of A and B . We calculate the eigenvalues of the full quadratic Hamiltonian matrix $[\mathcal{H}_{\text{eff,lin}}]_i +$

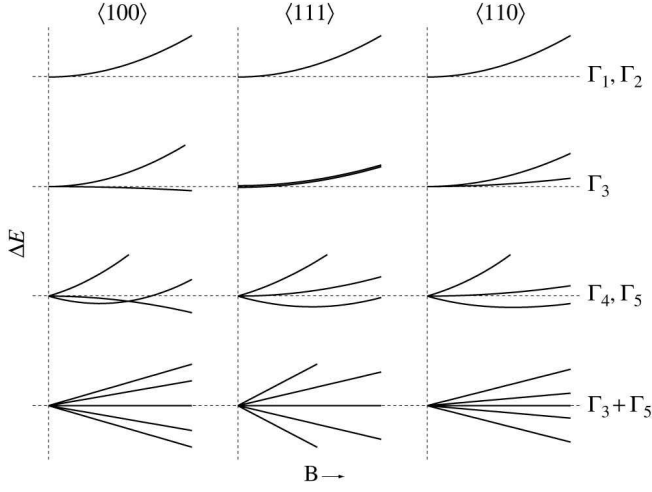


FIG. 1: Schematic overview of level splitting in a magnetic field along the main crystallographic axes in several kinds of two-hole acceptor levels. The figure illustrates the qualitative aspects of the splitting. The values of the parameter have been chosen to emphasize these features.

$[\mathcal{H}_{\text{eff,quad}}]_i$ for the three main crystallographic directions. For $\mathcal{B} \parallel \langle 100 \rangle$ we have

$$\Delta E = \begin{cases} \mu_B g \mathcal{B} + (a_i + b_i) \mathcal{B}^2 \\ (a_i - 2b_i) \mathcal{B}^2 \\ -\mu_B g \mathcal{B} + (a_i + b_i) \mathcal{B}^2 \end{cases}$$

For $\mathcal{B} \parallel \langle 111 \rangle$ we have

$$\Delta E = \begin{cases} \mu_B g \mathcal{B} + (a_i + \frac{1}{6}c_i) \mathcal{B}^2 \\ (a_i - \frac{1}{3}c_i) \mathcal{B}^2 \\ -\mu_B g \mathcal{B} + (a_i + \frac{1}{6}c_i) \mathcal{B}^2 \end{cases}$$

And for $\mathcal{B} \parallel \langle 110 \rangle$ we find

$$\Delta E = \begin{cases} \mathcal{B} \sqrt{\mu_B^2 g^2 + (\frac{1}{8}c_i + \frac{3}{4}b_i) \mathcal{B}^2} \\ + (a_i + \frac{1}{4}b_i + \frac{1}{8}c_i) \mathcal{B}^2 \\ (a_i - \frac{1}{2}b_i - \frac{1}{4}c_i) \mathcal{B}^2 \\ -\mathcal{B} \sqrt{\mu_B^2 g^2 + (\frac{1}{8}c_i + \frac{3}{4}b_i) \mathcal{B}^2} \\ + (a_i + \frac{1}{4}b_i + \frac{1}{8}c_i) \mathcal{B}^2 \end{cases}$$

It follows that in second order the splitting is no longer symmetric and isotropic for these levels.

The Zeeman effect of the levels treated so far is schematically illustrated in Fig. 1.

CENTRAL FIELD APPROXIMATION

Finally we discuss the Zeeman effect for two-hole states in the central field approximation. In this approximation, we must start from the one-hole levels and their behavior

in a magnetic field. The two-hole wave functions are antisymmetrized products of one-hole wave functions and the energy levels are obtained by examining the various ways to put the two holes in the one-hole levels.

We will present results for the case where both holes are put in a Γ_8 level and $\mathcal{B} \parallel \langle 100 \rangle$ only. Similar results for the other types of levels and other directions of the field are easily obtained in an analogous way.

For a magnetic field $\mathcal{B} \parallel \langle 100 \rangle$, the single hole Γ_8 ground state is split into Γ_5 , Γ_6 , Γ_7 and Γ_8 -levels of $\tilde{S}_4$ [6]. Because holes are fermions, each of these non-degenerate levels can be occupied by at most one hole. By putting each of the two holes in a different level, this gives rise to six two-hole levels $\Gamma_5 \times \Gamma_6 = \Gamma_1$, $\Gamma_5 \times \Gamma_7 = \Gamma_3$, $\Gamma_5 \times \Gamma_8 = \Gamma_2$, $\Gamma_6 \times \Gamma_7 = \Gamma_2$, $\Gamma_6 \times \Gamma_8 = \Gamma_4$, and $\Gamma_7 \times \Gamma_8 = \Gamma_1$, where all representations are of $\tilde{S}_4$.

The energy shifts of the single-hole levels have been determined experimentally [6]. The shifts of the two-hole levels can be calculated as the sum of the shifts of the individual single hole levels from which they are composed. This results in a linear shift for each two-hole level, given by $\mu_B g \mathcal{B}$, with $g = \frac{3}{2}g_{3/2} + \frac{1}{2}g_{1/2}$ for Γ_2 , $g = \frac{3}{2}g_{3/2} - \frac{1}{2}g_{1/2}$ for Γ_4 , $g = 0$ for $2\Gamma_1$, $g = -\frac{3}{2}g_{3/2} + \frac{1}{2}g_{1/2}$ for Γ_3 and $g = -\frac{3}{2}g_{3/2} - \frac{1}{2}g_{1/2}$ for Γ_2 . The parameters $g_{3/2}$ and $g_{1/2}$ are the g -factors for the single hole $j = \frac{3}{2}$ and $j = \frac{1}{2}$ -levels respectively. Experimental values for B^0 in Si are $g_{3/2} = 1.12$ and $g_{1/2} = 1.04$ [7]. In the above, a small overall shift is neglected.

APPLICATION TO B^+

Only states arising from $\{\Gamma_8 \times \Gamma_8\}$ (see Table II) are candidates for the B^+ ground state. These are Γ_1 , Γ_3 , Γ_5 , $\Gamma_3 + \Gamma_5$ and the unsplit (central field) $\{\Gamma_8 \times \Gamma_8\}$. Each of these five possibilities for the B^+ ground state will be compared to existing experimental data. From the previous section, we conclude that all possible ground state levels behave qualitatively differently in a magnetic field. Therefore, it is in principle possible to determine the nature of the actual ground state of B^+ from the analysis of a sufficiently detailed experiment. Though this approach is hampered by the fact that the value of the parameters are not known, it is possible to draw conclusions based on the qualitative characteristics, such as linear or quadratic splitting/shift and the asymmetry of the splitting.

We refer to our recent experiments reported in Ref. 4 and summarize the main observations. The ground state energy shifts upwards (that is, in the direction of the valence band) and is therefore diamagnetic. The shift has both a linear and a quadratic component. The total shift amounts to 1 meV at a magnetic field of 14 T and was equal for the $\langle 100 \rangle$ and $\langle 110 \rangle$ directions (see Fig. 2). The width of the observed peak (full width at half maximum)

increased from 1.2 meV to 1.5 meV in the same magnetic field range. Within the experimental error (~ 0.2 meV), no splitting of the peak was detected [21].

The experimentally observed super linear overall shift, independent from the direction of $\mathbf{B}$, best matches the behavior of a Γ_1 state, although this leaves the strong linear component in the measured magnetic field dependence unexplained. Therefore, we believe that the ground state of B^+ is indeed a Γ_1 state. This hypothesis does imply that the observed linear component in the peak shift and the peak broadening are due to other processes (e.g. the Stark effect) as already suggested in Ref. 4.

The broadening in the observed peak is linear in the magnetic field and independent of its direction. Therefore, it cannot be explained as unresolved splitting of a Γ_3 level. A Γ_5 or $\Gamma_3 + \Gamma_5$ ground state would give rise to linear splitting (broadening), but no overall shift would be expected in first order. Moreover, the magnitude of the splitting in a $\Gamma_3 + \Gamma_5$ level would depend on the magnetic field direction. Therefore, these possibilities are not consistent with the experimental observations. Only when the parameter a_3 (a_5) would much larger than all other relevant parameters (that is $a_3 \ll b_3$ or $a_5 \ll b_5, c_5, \mu_b g/B$), the magnetic field dependence of the Γ_3 (Γ_5) state would be similar to that of the Γ_1 state. In that case, Γ_3 , Γ_5 and $\Gamma_3 + \Gamma_5$ states cannot be rejected as potential ground state symmetries for B^+ .

The central field approach is unlikely to yield good results for B^+ , for which the wave functions of the two holes are expected to overlap considerably (due to the small nuclear charge). The peak splitting (or broadening, due to unresolved splitting) expected in this approach between the two Γ_2 levels would be given by $2\mu_B(\frac{3}{2}g_{3/2} + \frac{1}{2}g_{1/2})B$. Assuming the B^0 -values of the g -factors are valid here, this would amount to 3.6 meV for $B = 14$ T. This is much larger than the observed 0.3 meV increase of the FWHM of the measured resonance peak. Moreover, the 1 meV shift observed in the experiment is much larger than the expected overall peak shift in this approach. Therefore, the description of the B^+ ground state in the central field approximation is not consistent with the experimental observations.

In summary, magnetic field dependent measurements indicate that the B^+ ground state is a non-degenerate Γ_1 state. It would be interesting to have higher resolution spectroscopy data available, in order to exclude that the observed peak broadening is due to unresolved splitting. Knowledge of the B^+ ground state wave function would allow for obtaining quantitative information about the phenomenological parameters, which would be advantageous in the interpretation of experimental data.

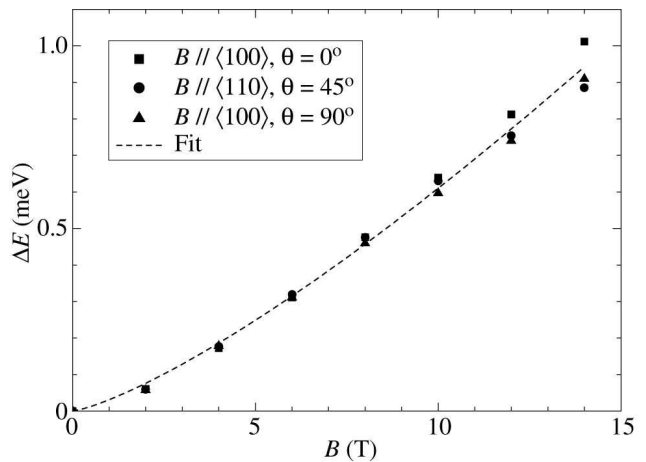


FIG. 2: Magnetic field induced shift of the B^+ ground state deduced from electrical transport measurements [4]. The angle between the magnetic field and the current is denoted by θ . The expression $\Delta E \propto B(1 + \alpha B)$ was fit to the data, yielding $\alpha = 0.046 \text{ T}^{-1}$.

CONCLUSIONS

In conclusion, we have presented a general group theoretical study of the magnetic field dependence of two-hole states of acceptors in tetrahedral semiconductors. We have used our results to analyze recent experimental observations. This analysis indicates that the B^+ ground state is most compatible with a Γ_1 state.

We thank I. D. Vink for useful discussions. One of us, S.R., wishes to acknowledge the Royal Netherlands Academy of Arts and Sciences for financial support. This work is part of the research program of the Stichting voor Fundamenteel Onderzoek der Materie, which is financially supported by the Nederlandse Organisatie voor Wetenschappelijk Onderzoek.

* Electronic address: g.d.j.smit@tnw.tudelft.nl

† Electronic address: s.rogge@tnw.tudelft.nl

- [1] P. Norton, Phys. Rev. Lett. **37**, 164 (1976).
- [2] B. E. Kane, Nature **393**, 133 (1998).
- [3] W. Burger and K. Lassmann, Phys. Rev. Lett. **53**, 2035 (1984).
- [4] J. Caro, I. D. Vink, G. D. J. Smit, S. Rogge, T. M. Klapwijk, R. Loo, and M. Caymax (2003), submitted.
- [5] A. Ramdas and S. Rodriguez, Rep. Prog. Phys. **44**, 1297 (1981).
- [6] A. K. Bhattacharjee and S. Rodriguez, Phys. Rev. B **6**, 3836 (1972).
- [7] F. Merlet, B. Pajot, P. Arcas, and A. M. Jean-Louis, Phys. Rev. B **12**, 3297 (1975).
- [8] E. Kartheuser and S. Rodriguez, Phys. Rev. B **8**, 1556 (1973).
- [9] A. V. Rodina, Solid-State Comm. **85**, 23 (1993).
- [10] F. S. Ham and C.-H. Leung, Phys. Rev. Lett. **71**, 3186

- (1993).
- [11] F. S. Ham and C.-H. Leung, Solid-State Comm. **93**, 375 (1995).
 - [12] N. Sugimoto, S. Narita, M. Taniguchi, and M. Kobayashi, Solid-State Comm. **30**, 395 (1979).
 - [13] P. Gross and K. Lassmann, Ann. Phys. **4**, 503 (1995).
 - [14] S. Roshko and W. Dietsche, Solid-State Comm. **98**, 453 (1996).
 - [15] B. S. Tsukerblat, *Group theory in chemistry and spectroscopy*, Theoretical chemistry (Academic press Ltd., London, 1994).
 - [16] J. M. Luttinger, Phys. Rev. **102**, 1030 (1956).
 - [17] S. Washimiya, K. Shinagawa, and S. Sugano, Phys. Rev. B **1**, 2976 (1970).
 - [18] G. F. Koster, J. O. Dimmock, R. G. Wheeler, and H. Satz, *Properties of the thirty-two point groups* (M.I.T. Press, Cambridge, 1963).
 - [19] But not necessarily in a first order approach.
 - [20] Because $\Gamma_3 \times \Gamma_5 = \Gamma_4 + \Gamma_5$ it is possible (e.g. by using the coupling coefficients for $\Gamma_3 \times \Gamma_5$ as given in Ref.18 and inverting) to express all six possible products of Γ_3 and Γ_5 wave functions as a linear combination of Γ_4 and Γ_5 wave functions. Using the Wigner-Eckart orthogonality theorem and the fact that all operators occurring in the linear Zeeman Hamiltonian transform according to the rows of Γ_4 , the matrix form can be derived.
 - [21] In these experiments the concentration of B-impurities in the silicon was so high that they cannot be considered as fully isolated as proven by the increased binding energy of the second hole in the B^+ -state. The interaction of a B^+ state with neighboring B^0 states is however not expected to change the nature of its ground state.